NSN 5962-01-364-1998

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Programmed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Bipolar metal-oxide semiconductor

Case Outline Source And Designator:

D-2 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Biploar prom

Voltage Rating And Type Per Characteristic:

5.5 volts absolute input and 7.0 volts absolute input

Memory Device Type:

Prom

Test Data Document:

49956-979735-106 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Specification Data:

96906-mil-std-883/tx/ government standard

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0